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Vishay Semiconductors

COMPLIANT

Medium Power Silicon Rectifier Diodes, (Stud Version), 12 A



DO-203AA (DO-4)

| PRODUCT SUMMARY | | | |
|-----------------------|-----------------|--|--|
| I _{F(AV)} | 12 A | | |
| Package | DO-203AA (DO-4) | | |
| Circuit configuration | Single diode | | |

FEATURES

- Voltage ratings from 50 V to 1000 V
- High surge capability
- Low thermal impedance
- High temperature rating
- Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-----------------|------------|------------------|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | |
| I _{F(AV)} | | 12 | A | | |
| | T _C | 150 | °C | | |
| I _{FSM} | 50 Hz | 230 | ^ | | |
| | 60 Hz | 240 | Α | | |
| l ² t | 50 Hz | 260 | A ² s | | |
| | 60 Hz | 240 | A ^z S | | |
| TJ | | -65 to 200 | °C | | |
| V _{RRM} | Range | 50 to 1000 | V | | |

Note

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | |
|-----------------|--|---|--|--|
| TYPE NUMBER | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _C = -65 °C TO 200 °C) V | $V_{R(RMS)}$, MAXIMUM RMS REVERSE VOLTAGE ($T_{C} = -65 ^{\circ}\text{C}$ TO 200 $^{\circ}\text{C}$) | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE (T _C = -65 °C TO 200 °C) V | V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE ($T_C = -65~^{\circ}C$ TO 200 $^{\circ}C$) |
| VS-1N1199A | 50 | 35 | 100 | 50 |
| VS-1N1200A | 100 | 70 | 200 | 100 |
| VS-1N1201A | 150 | 105 | 300 | 150 |
| VS-1N1202A | 200 | 140 | 350 | 200 |
| VS-1N1203A | 300 | 210 | 450 | 300 |
| VS-1N1204A | 400 | 280 | 600 | 400 |
| VS-1N1205A | 500 | 350 | 700 | 500 |
| VS-1N1206A | 600 | 420 | 800 | 600 |
| VS-1N3670A | 700 | 490 | 900 | 700 |
| VS-1N3671A | 800 | 560 | 1000 | 800 |
| VS-1N3672A | 900 | 630 | 1100 | 900 |
| VS-1N3673A | 1000 | 700 | 1200 | 1000 |

Notes

- JEDEC registered values are in bold
- Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA

JEDEC[®] registered values are in bold



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| FORWARD CON | 10011011 | CVMPOL | TEST OF | NUDITIONS | VALUEO | LINUTO |
|--|---------------------------|-----------------------------------|---|--|-----------|------------------|
| PARAMETER | | SYMBOL | TEST CC | ONDITIONS | VALUES | UNITS |
| Maximum average forward current at case temperature | | I _{F(AV)} | 180° sinusoidal conduction | | 12 150 | °C |
| Maximum peak one cycle non-repetitive surge current | | I _{FSM} | Half cycle 50 Hz sine wave or 6 ms rectangular pulse | Following any rated load condition and with rated VRRM applied | 230 | А |
| | | | Half cycle 60 Hz sine wave or 5 ms rectangular pulse | | 240 | |
| | | | Half cycle 50 Hz sine wave or 6 ms rectangular pulse | Following any rated load condition and with V _{RRM} applied following surge = 0 V | 275 | |
| | | | Half cycle 60 Hz sine wave or 5 ms rectangular pulse | | 285 | |
| | | | t = 10 ms | With rated V _{RRM} applied | 260 | |
| Maximum I ² t for fusing | | l ² t | t = 8.3 ms | following surge, initial T _J = 200 °C | 240 | A ² s |
| Maximum I ² t for individual | | | t = 10 ms | With V _{RRM} = 0 V following | 370 | |
| device fusing | | | t = 8.3 ms | surge, initial T _J = 200 °C | 340 | |
| Maximum I ² √t for individual device fusing | | I ² √t ⁽¹⁾ | t = 0.1 ms to 10 ms, V _{RRM} = 0 V following surge | | 3715 | A²√s |
| Maximum forward voltage drop | | V_{FM} | I _{F(AV)} = 12 A (38 A peak), T _C = 25 °C | | 1.35 | V |
| | $V_{RRM} = 50 \text{ V}$ | | Maximum rated I _{F(AV)} and T _C | | 3.0 | mA |
| | V _{RRM} = 100 V | | | | 2.5 | |
| | V _{RRM} = 150 V | | | | 2.25 | |
| | V _{RRM} = 200 V | I _{R(AV)} ⁽²⁾ | | | 2.0 | |
| | V _{RRM} = 300 V | | | | 1.75 | |
| Maximum average reverse current | V _{RRM} = 400 V | | | | 1.5 | |
| | V _{RRM} = 500 V | | | | 1.25 | |
| | V _{RRM} = 600 V | | | | 1.0 | |
| | V _{RRM} = 700 V | | | | 0.9 | |
| | V _{RRM} = 800 V | | | | 0.8 | |
| | V _{RRM} = 900 V | | | | 0.7 | |
| | V _{RRM} = 1000 V |] | | | 0.6 | |

Notes

- JEDEC registered values are in bold
- (1) I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$
- (2) Maximum peak reverse current (I_{RM}) under same conditions $\approx 2 \text{ x rated } I_{R(AV)}$

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|---|---------|-----------------------------------|--|--------------|---------------------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum operating case and storage temperature range | | T _C , T _{Stg} | | -65 to 200 | °C |
| Maximum internal thermal resistance, junction to case | | R _{thJC} | DC operation | 2.0 | °C/W |
| Thermal resistance, case to sink | | R _{thCS} | Mounting surface, smooth, flat and greased | 0.5 | C/VV |
| | minimum | | Torque applied to nut; non-lubricated threads | 1.36 (12) | N · m (lbf · in) |
| | maximum | | Torque applied to flut, flori-lubricated tilleads | 1.69 (15) | |
| Mounting torque | minimum | | Targue applied to put Jubricated threads | 1.07 (9.45) | |
| Mounting torque | maximum | | Torque applied to nut; lubricated threads | 1.30 (11.55) | |
| | minimum | | Tarana and indicate desire and the indicate defense de | 1.17 (10.35) | |
| | maximum | | Torque applied to device case; lubricated threads | 1.43 (12.65) | |
| Approximate weight | | | | 7.0 | g |
| | | | | 0.25 | OZ. |
| Case style | | | JEDEC | DO-203A | A (DO-4) |

Note

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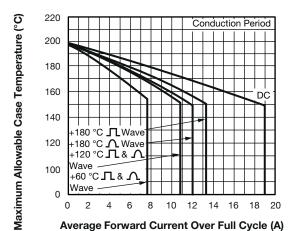


Fig. 1. Assessed Females Commenters

Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature

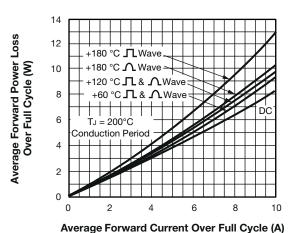


Fig. 2 - Maximum Low Level Forward Power Loss vs. Average Forward Current

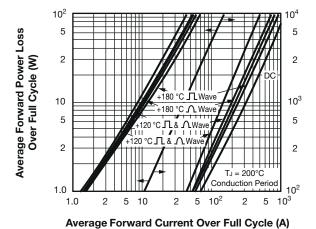


Fig. 3 - Maximum High Level Forward Power Loss vs. Average Forward Current

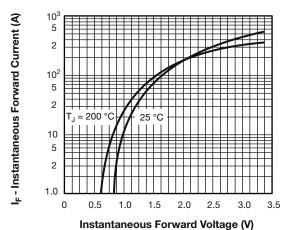


Fig. 4 - Maximum Forward Voltage vs. Forward Current

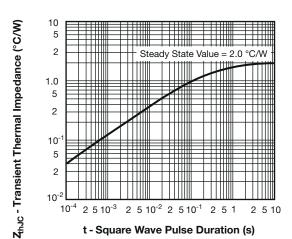
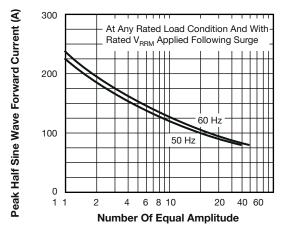


Fig. 5 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration



Half Cycle Current Pulses (N)
Fig. 6 - Maximum Non-Repetitive 50 Hz Surge Current vs.
Number of Current Pulses

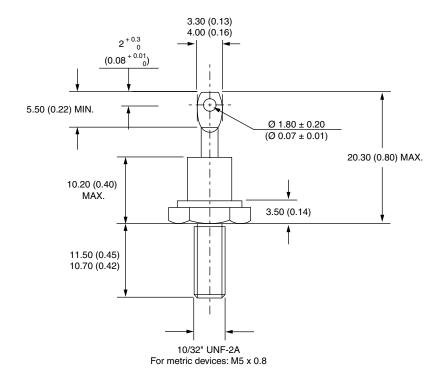
| LINKS TO RELATED DOCUMENTS | | | |
|----------------------------|--------------------------|--|--|
| Dimensions | www.vishay.com/doc?95311 | | |

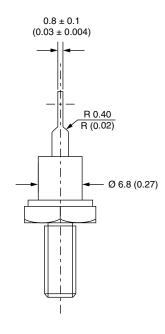


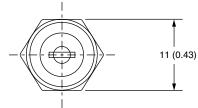
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DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)









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